

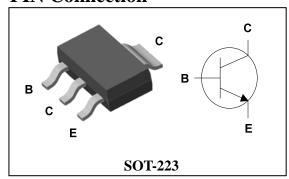
# **STC401Q**

**NPN Silicon Transistor** 

#### **Features**

- Low saturation switching application
- Voltage regulator application
- Low saturation : V<sub>CE(SAT)</sub>=0.4V Max.
- High Voltage : V<sub>CEO</sub>=60V Min.

### **PIN Connection**



### **Ordering Information**

Type NO.	Marking	Package Code	
STC401Q	STC401 YWW	SOT-223	

STC401: DEVICE CODE, YWW(Y: Year code, WW: Weekly code)

### **Absolute maximum ratings**

Characteristic	Symbol	Ratings	Unit	
Collector-Base voltage	$V_{CBO}$	80	V	
Collector-Emitter voltage	$V_{\sf CEO}$	60	V	
Emitter-base voltage	$V_{EBO}$	5	V	
Collector ourment	I <sub>C</sub>	1	A(DC)	
Collector current	I <sub>CP</sub> *	2	A(Pulse)	
	P <sub>C</sub>	1.1	10/	
Collector dissipation	Pc**	1.5	W	
Junction temperature	Tj	150	°C	
Storage temperature	T <sub>stg</sub>	-55~150	°C	

<sup>\*:</sup> Single pulse, tp= 300  $\mu$ s

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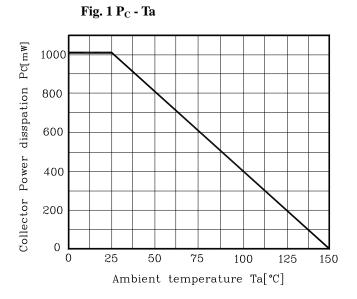
<sup>\*\*:</sup> When mounted on ceramic substrate(250 mm²×0.8t)

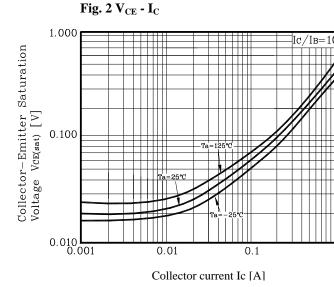
# **Electrical Characteristics**

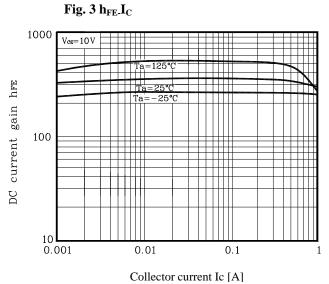
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	BV <sub>CBO</sub>	I <sub>C</sub> =100 μ <sup>A</sup> , I <sub>E</sub> =0	80	-	-	V
Collector-Emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	60	-	-	V
Emitter-Base breakdown voltage	BV <sub>EBO</sub>	I <sub>E</sub> =10mA, I <sub>C</sub> =0	5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 60V, I_{E} = 0$	-	-	0.1	μА
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0	-	-	0.1	μА
DO	h *	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	200	-	400	
DC current gain	h <sub>FE</sub> *	$V_{CE}=2V$ , $I_{C}=1A$	80	-	-	ı
Base-Emitter on voltage	V <sub>BE(ON)</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =500mA	-	-	1.2	٧
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA	-	-	0.4	V
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz	-	10	-	pF
Transition frequency	f <sub>T</sub>	V <sub>CB</sub> =10V, I <sub>C</sub> =50mA	-	160	-	MHz

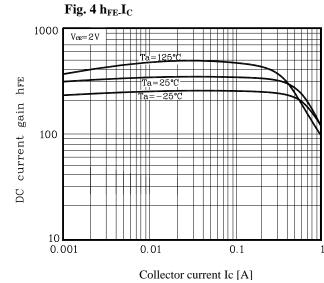
<sup>\*</sup> h<sub>FE</sub> rank : 200~400 Only

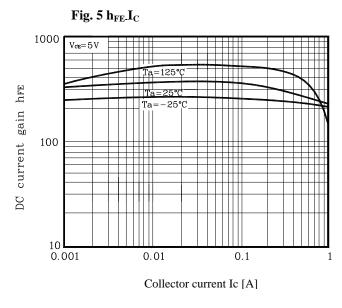
### **Electrical Characteristic Curves**

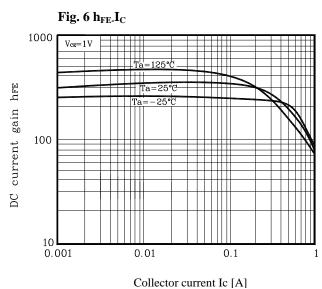












### **Electrical Characteristic Curves**

Fig. 7 Cob - V<sub>CB</sub> 100 Collector Output Capacitance Cob  $[\,\mathrm{pF}]$ f=1MHz10

Collector-Base voltage Vcb [V]

Fig. 9  $f_T$  -  $I_C$ 

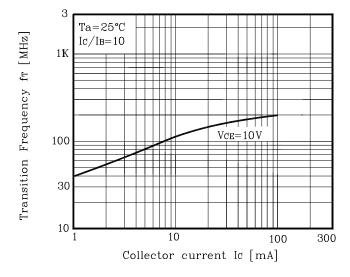


Fig. 8  $I_C$  -  $V_{CE}$ 

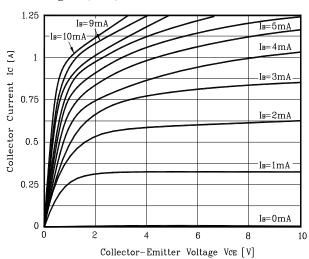
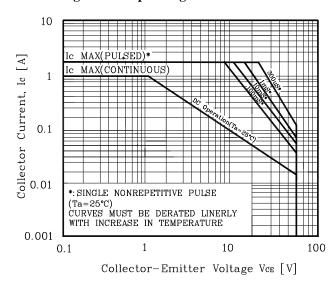
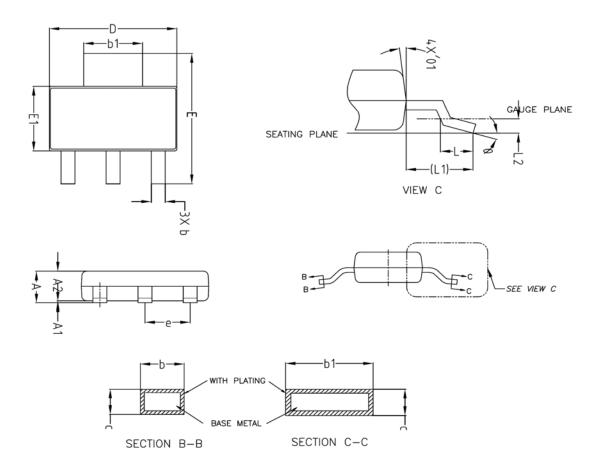


Fig. 10 Safe operating Area



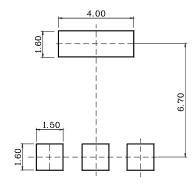
100

## **Outline Dimension**



	MILLIMETERS			NOTE
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	INOIE
Α	_	_	1.80	
A1	0.00	_	0.10	
A2	1.60	1.65	1.70	
Ь	0.68	_	0.76	
Ь1	2.95	_	3.07	
С	0.23	_	0.28	
D	6.40	6.50	6.60	
Ε	6.80	7.00	7.20	
E1	3.40	3.50	3.60	
е		2.30 BSC		
L	0.45	_	0.65	
L1		1.75 REF		
L2		0.10 BSC		
Ф	0,	_	10°	
<del>0</del> 1	5*	_	10°	

#### \* Recommend PCB solder land [Unit: mm]



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